

# DC-DC Converters Using GaN for Collider Physics Detectors

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**ECPE SiC & GaN User Forum:** Potential of Wide Bandgap Semiconductors in Power Electronic Applications

ECPE: European Center for Power Electronics e.V.

1 - 2 September 2011, Birmingham, U.K.

# Topics Agenda

- ❖ CERN: Current Detectors & Powering CMS ECAL detector
- ❖ Environment: Magnetic field & Radiation
- ❖ Limits of Silicon
- ❖ Why GaN ?
- ❖ GaN Tests
- ❖ Linear Collider – Low radiation but needs lower mass powering
- ❖ Market Trends
- ❖ Summary Keep Environment cool

# Large Hadron Collider

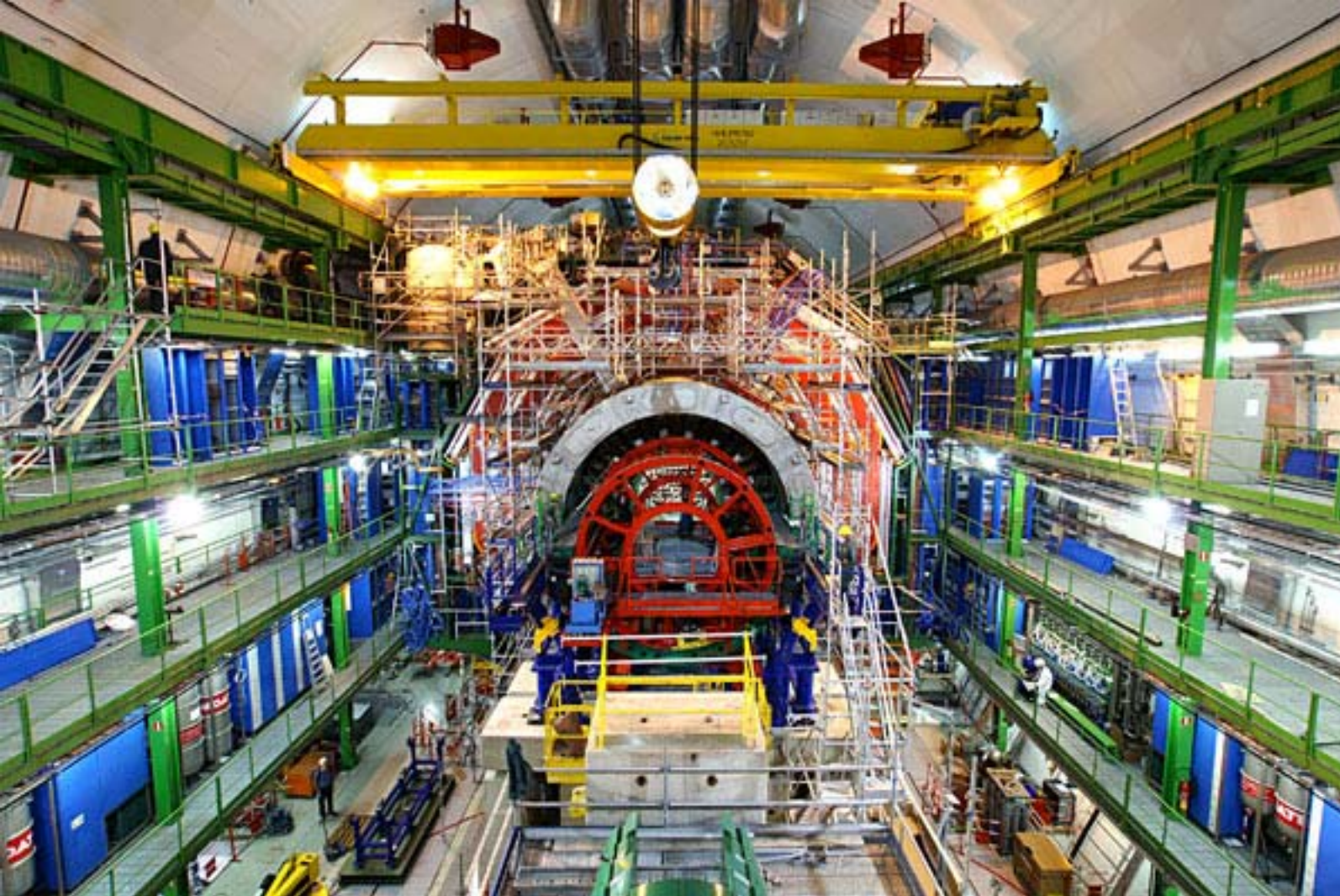


- 16 Mile proton-proton collider
- Tunnel as deep as 100 meters underground
- Four main experiments: *Atlas*, *CMS*, *LHCb*, and *Alice*





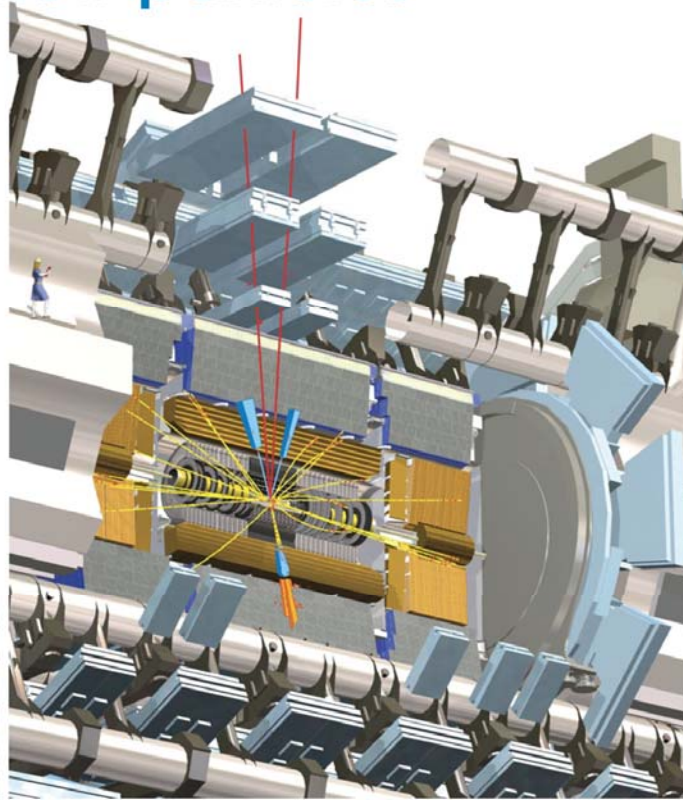
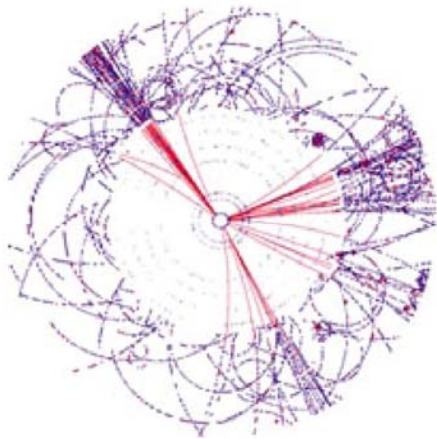
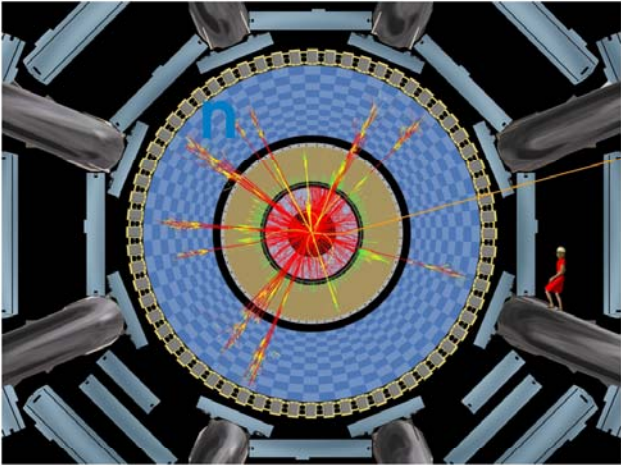








# Various views of a proton-proton collision creating many new particles





37 Countries, 155 Institutes, 2000 scientists (including about 400 students)    October 2006

**TRIGGER, DATA ACQUISITION  
& OFFLINE COMPUTING**

Austria, Brazil, CERN, Finland, France, Greece,  
Hungary, Ireland, Italy, Korea, Poland,  
Portugal, Switzerland, UK, USA

**TRACKER**

Austria, Belgium, CERN, Finland, France, Germany,  
Italy, Japan\*, Mexico, New Zealand, Switzerland, UK, USA

**CRYSTAL ECAL**

Belarus, CERN, China, Croatia, Cyprus, France, Italy,  
Japan\*, Portugal, Russia, Serbia, Switzerland, UK, USA

**PRESHOWER**

Armenia, CERN, Greece,  
India, Russia, Taiwan

**RETURN YOKE**

Barrel: Czech Rep., Estonia, Germany, Greece, Russia  
Endcap: Japan\*, USA

**SUPERCONDUCTING  
MAGNET**

All countries in CMS contribute  
to Magnet financing in particular:  
Finland, France, Italy, Japan\*,  
Korea, Switzerland, USA

**HCAL**

Barrel: Bulgaria, India, Spain\*, USA  
Endcap: Belarus, Bulgaria, Georgia, Russia,  
Ukraine, Uzbekistan  
HO: India

**FEET**

Pakistan  
China

**FORWARD  
CALORIMETER**

Hungary, Iran, Russia, Turkey, USA

**MUON CHAMBERS**

Barrel: Austria, Bulgaria, CERN, China,  
Germany, Hungary, Italy, Spain,  
Endcap: Belarus, Bulgaria, China, Colombia,  
Korea, Pakistan, Russia, USA

\* Only through  
industrial contracts

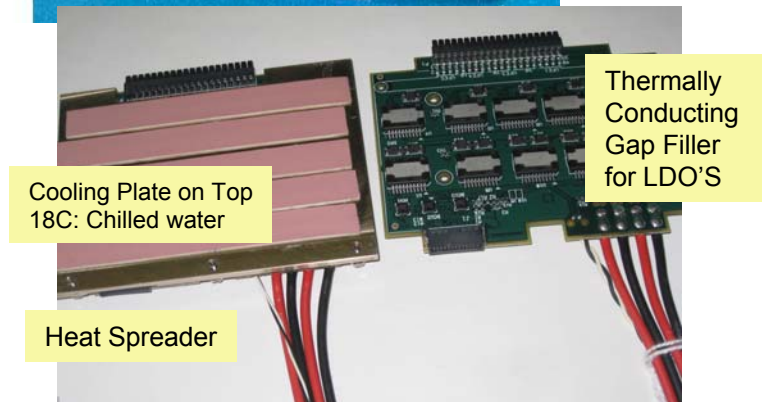
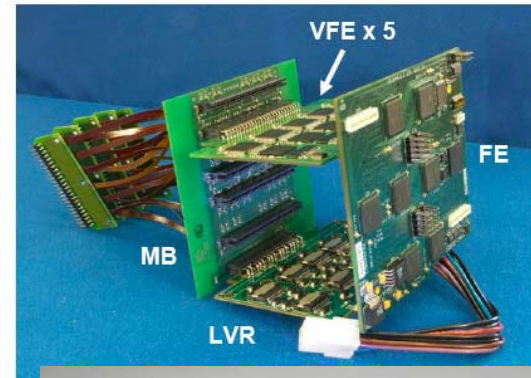
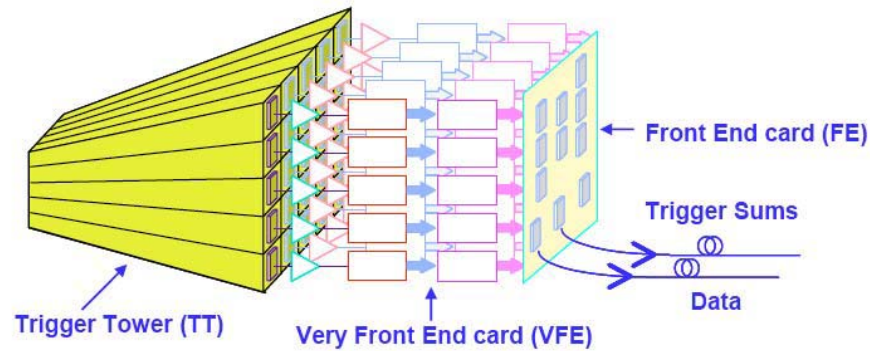
**Total weight** : 12500 T  
**Overall diameter** : 15.0 m  
**Overall length** : 21.5 m  
**Magnetic field** : 4 Tesla



# 20th Century State of Power Distribution – LHC Detectors

ECAL readout system was:

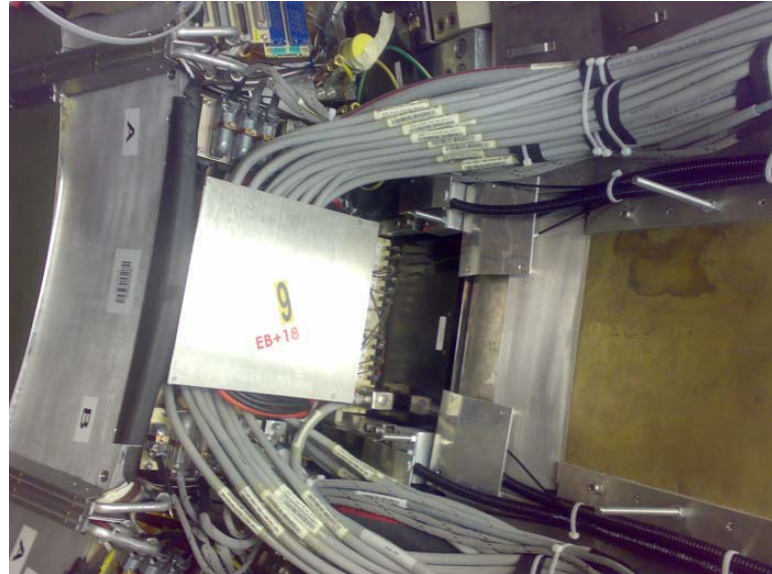
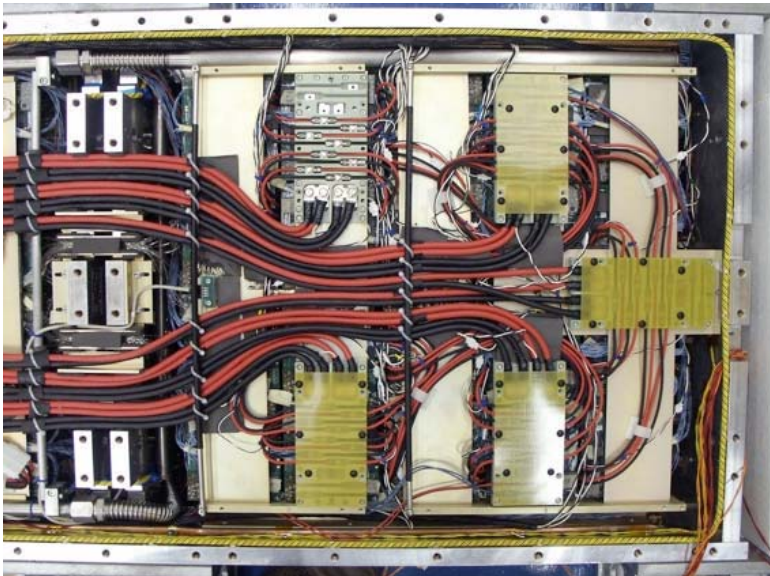
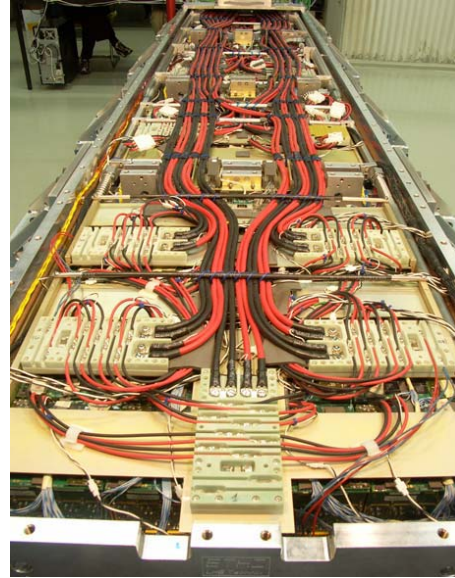
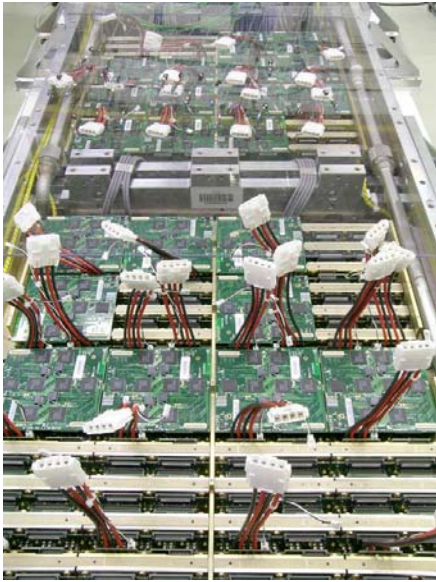
- designed in ~2000
- produced in 2001-2007
- commissioned in 2006-2007



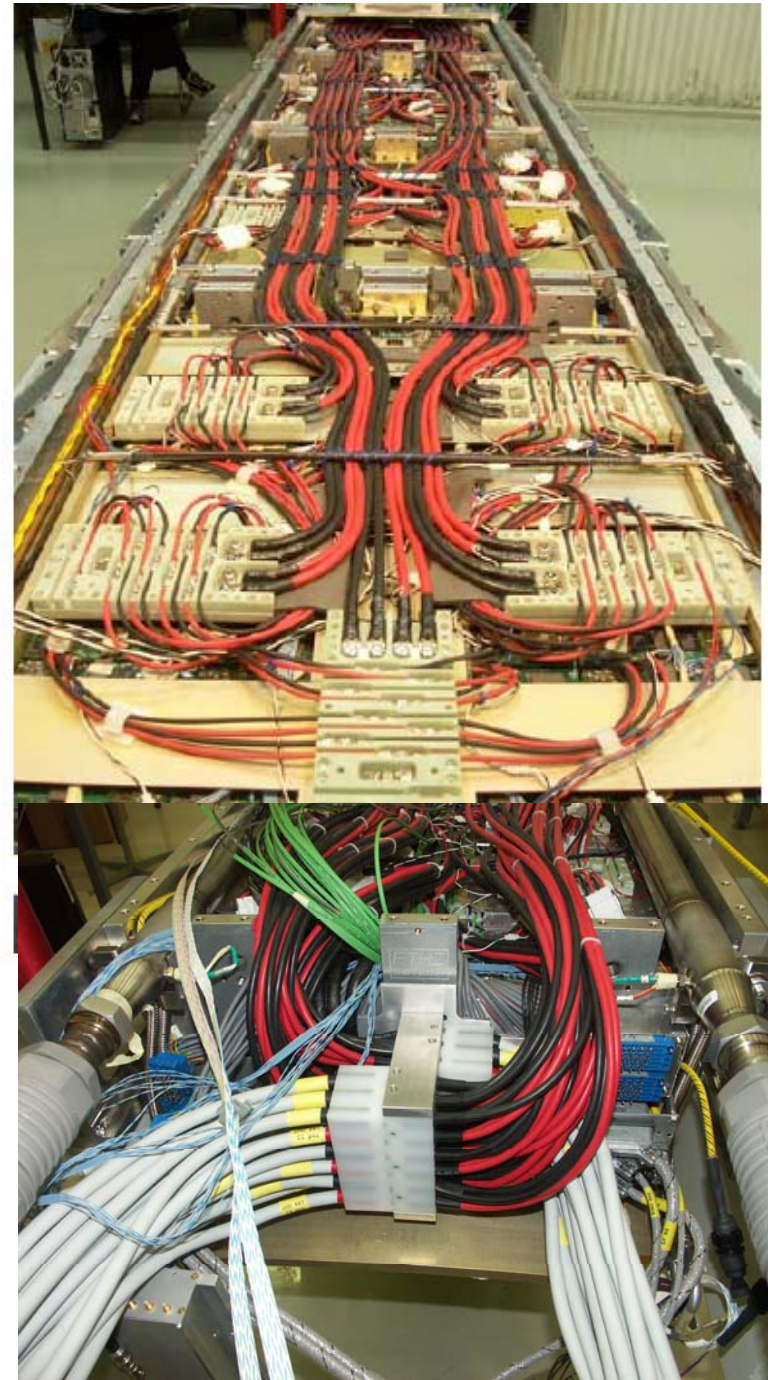
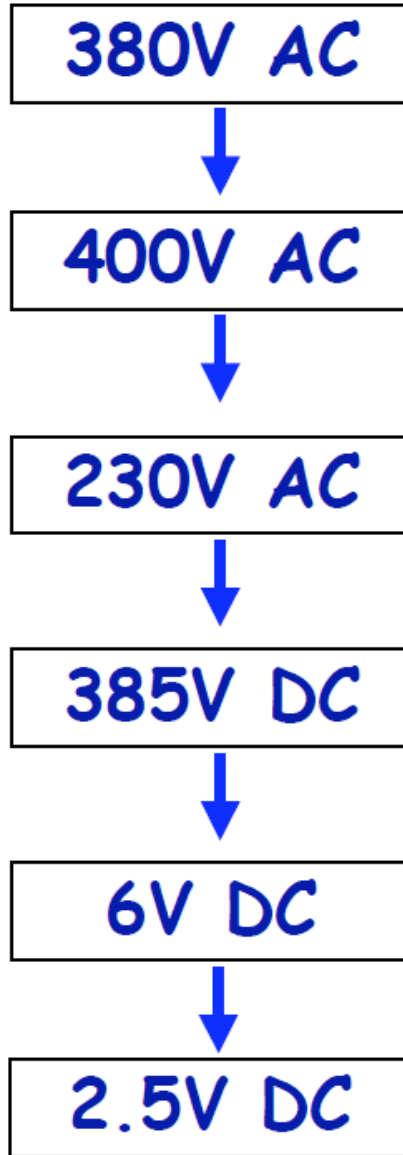
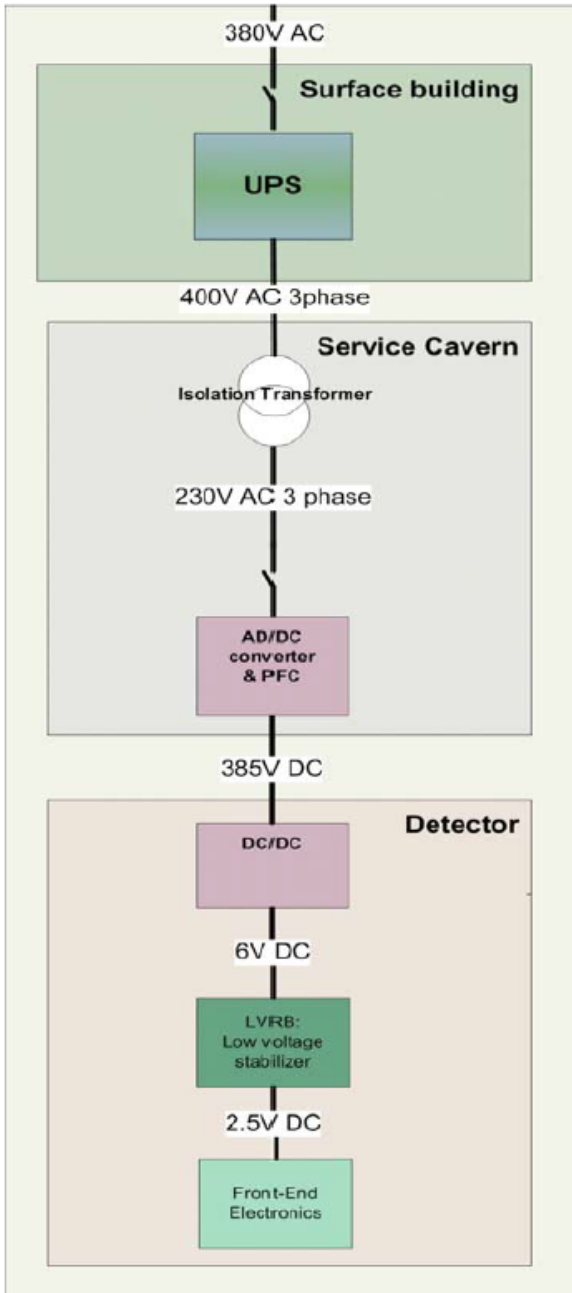
FE produces distributed heat low W/sq cm  
Power Boards High W/sq cm. use heat spreaders



# CMS ECAL Super modules

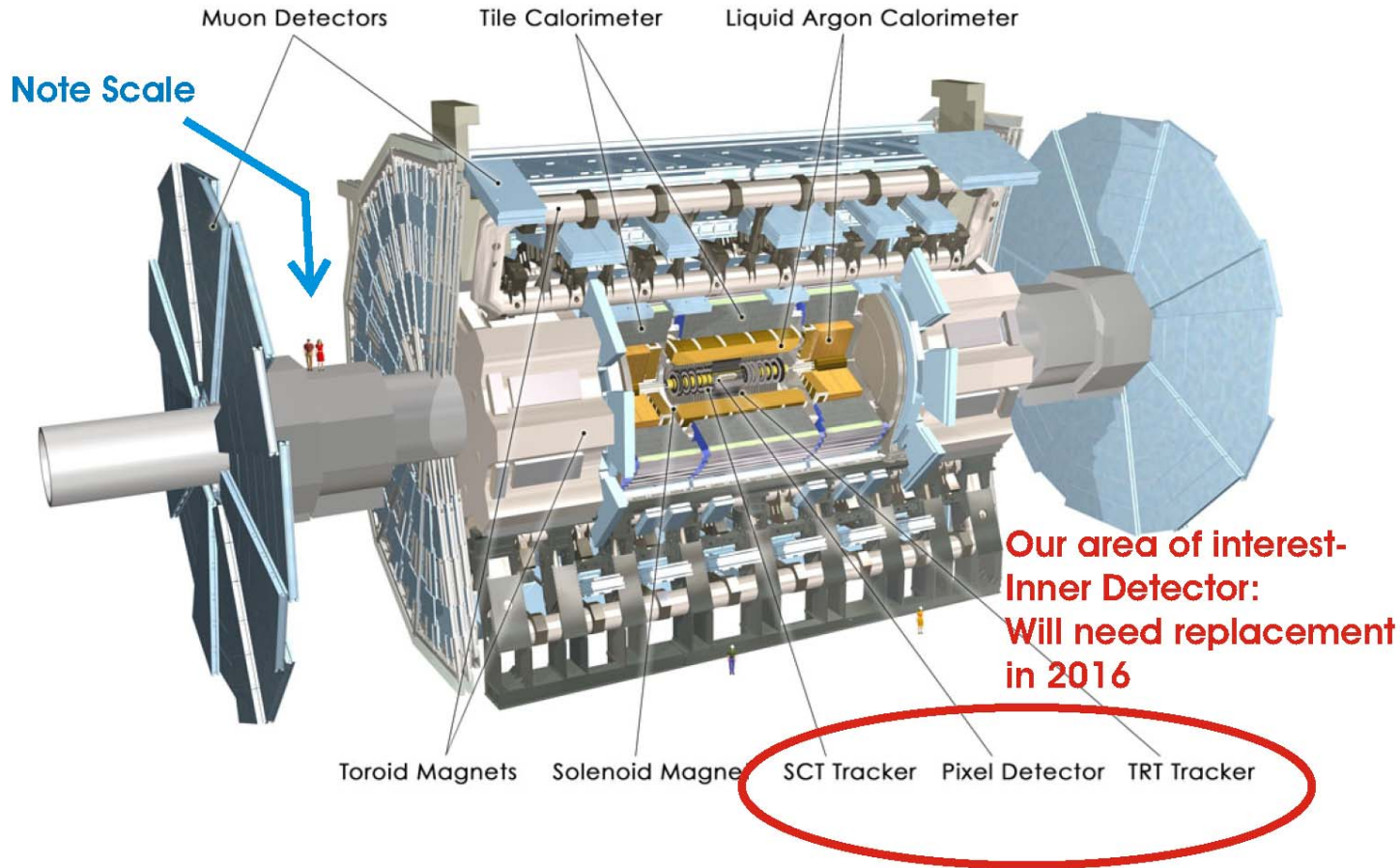




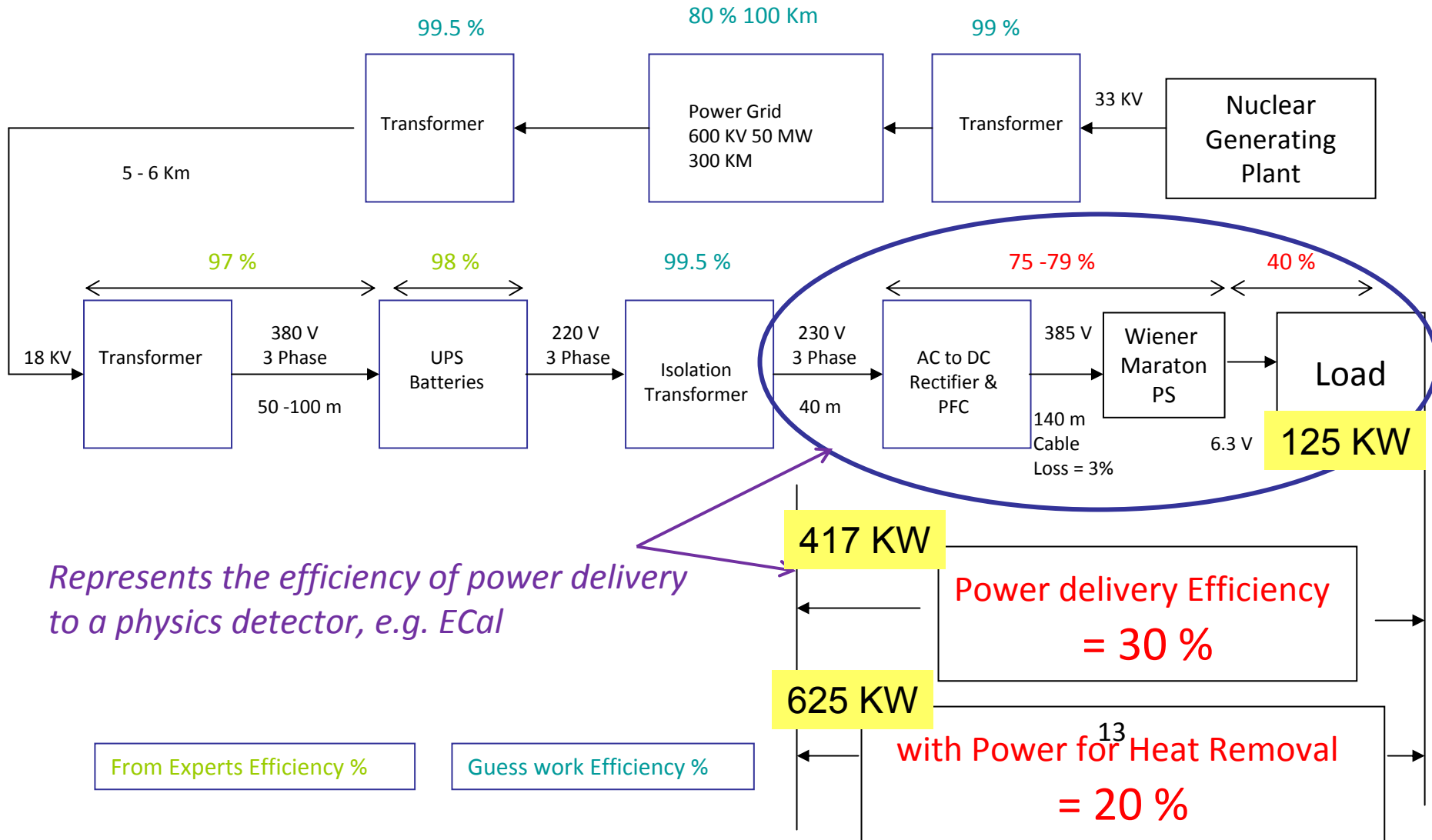




# Atlas Detector Consists of Many Sub-Detectors

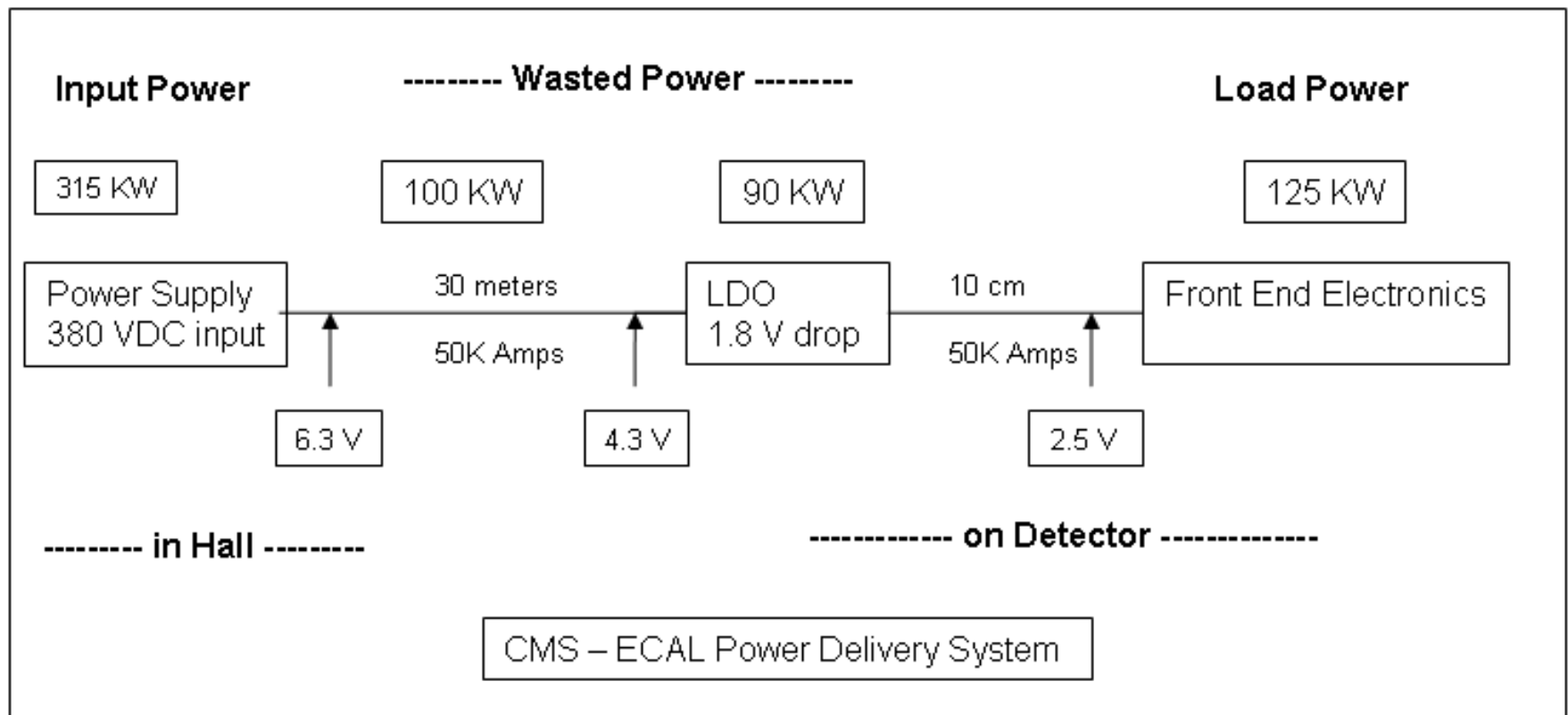


# Power Chain Efficiency for CMS ECAL



*It takes 2 watts of power to remove 1 watt of heat load*

# Power Efficiency \_ Inefficiency \_ Wasted Power





# Is there a better way to deliver power?

## HV – Low Voltage Converters: Reduce cable delivery losses

- Power Supply cables 30 – 140 meters
- Point of Load Regulators
- DC-DC Buck Converters
- Other schemes are not feasible due to constraints
- Radiation, Magnetic Field (Air Core Coils), Switching Noise, Low Mass

## Collider Detector Power Essential

Sub-Systems operate:

**Magnetic Field:** ATLAS = 2 T: CMS = 4 T

: Outside Magnet 0.1 to 1 T at location of power supplies

**Radiation Tolerance:** Highest for trackers ~ 100 (Strips) Mrads

500 (Pixels) Mrads

~ 1 Mrad for outer sub systems

**Radiation Testing:** Test with Gammas – Cobalt 60 Source

**Protons** 800 MeV

**Neutrons** 1 MeV (Equivalent)  $1 \times 10^{15}$  n/cm<sup>2</sup> from research Nuclear Reactors

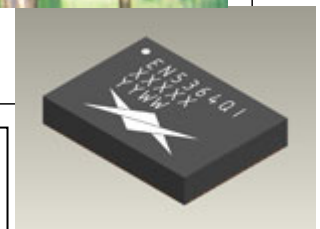
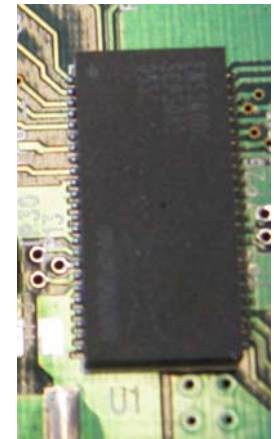
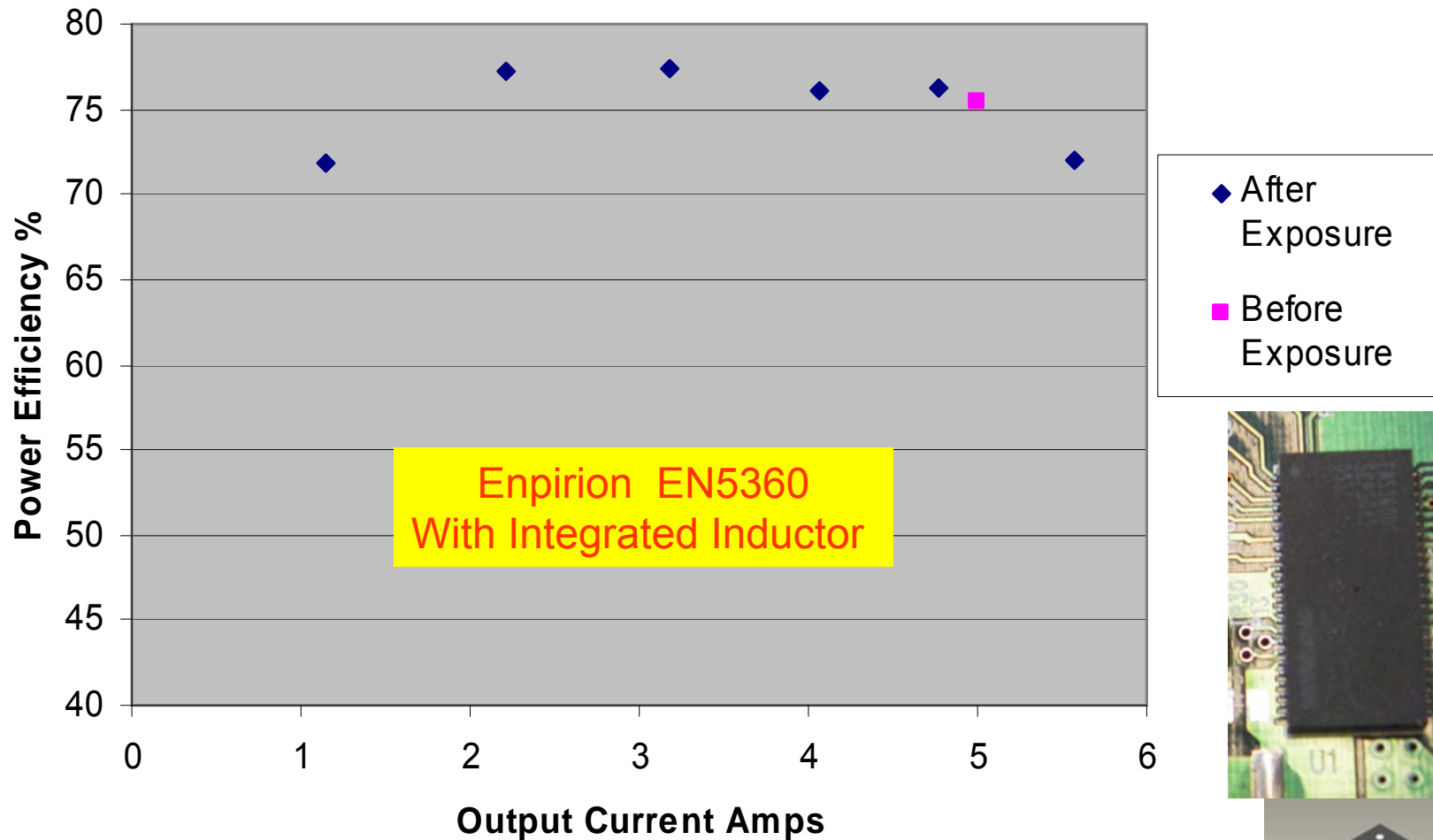
**Heavy Ions** produced here are low energy & do not penetrate IC lids

**Cooling:** Chilled Water, Evaporative Cooling – 5C

Future Liquid Carbon Dioxide -30C

**Minimize Material :** Radiation length causes extra (noise) tracks

## Buck Regulator Efficiency after 100 Mrad dosage

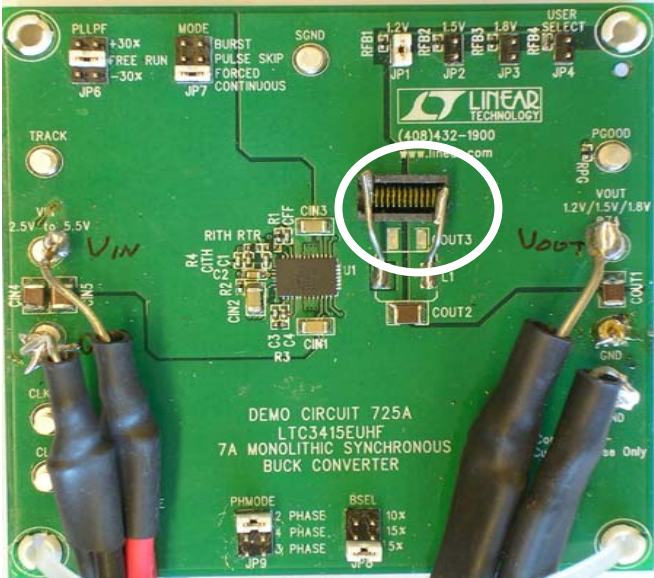


Found out at Power Technology conference 0.25  $\mu\text{m}$  Lithography

- Irradiated Stopped on St. Valentines Day 2007
- We reported @ TWEPP 2008 - IHP was foundry for EN5360



# Buck Converter with Air Coil



## Magnetic Field Effect

7 Tesla Field Chemistry Department  
Super Conducting Magnet in  
Persistence Mode

Effect:

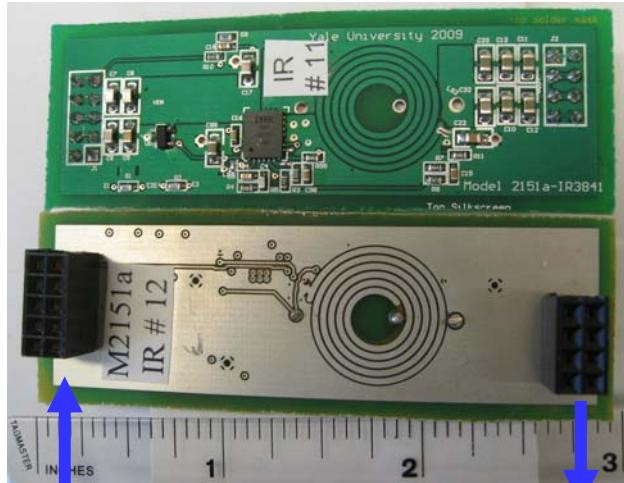
$V_{out} = 3.545$  Outside

$V_{out} = 3.546$  Edge of magnet

$V_{out} = 3.549$  Center of magnet

Change = Increased  $V_{out}$  1 part in 900 at 7T

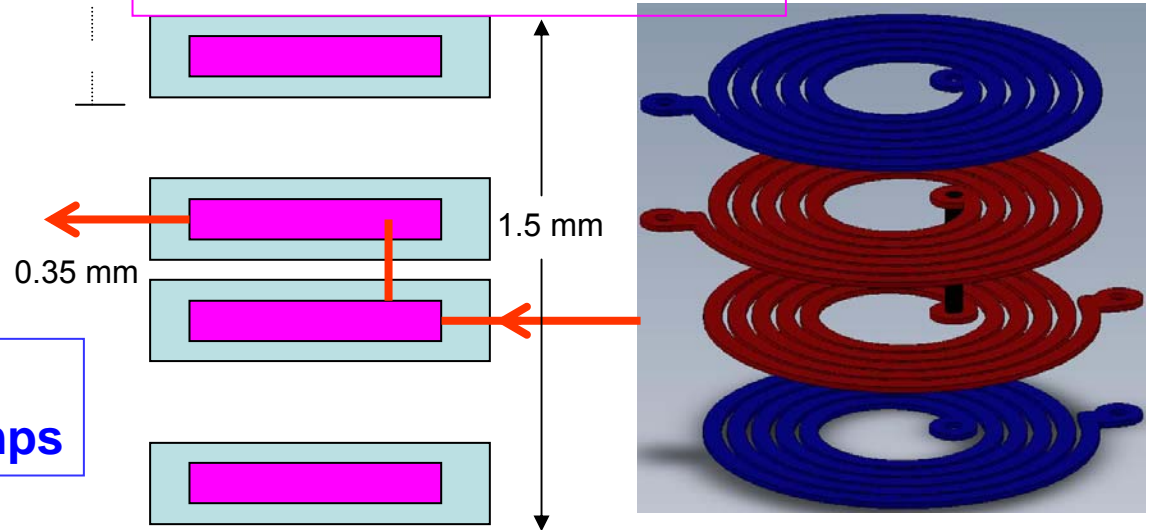
# Plug In Card with Shielded Buck Inductor



12 V

2.5 V  
@ 6 amps

Coupled Air Core Inductor  
Connected in Series



Spiral Coils Resistance in mΩ

|                 | Top  | Bottom |
|-----------------|------|--------|
| 3 Oz PCB        | 57   | 46     |
| 0.25 mm Cu Foil | 19.4 | 17     |

## Different Versions

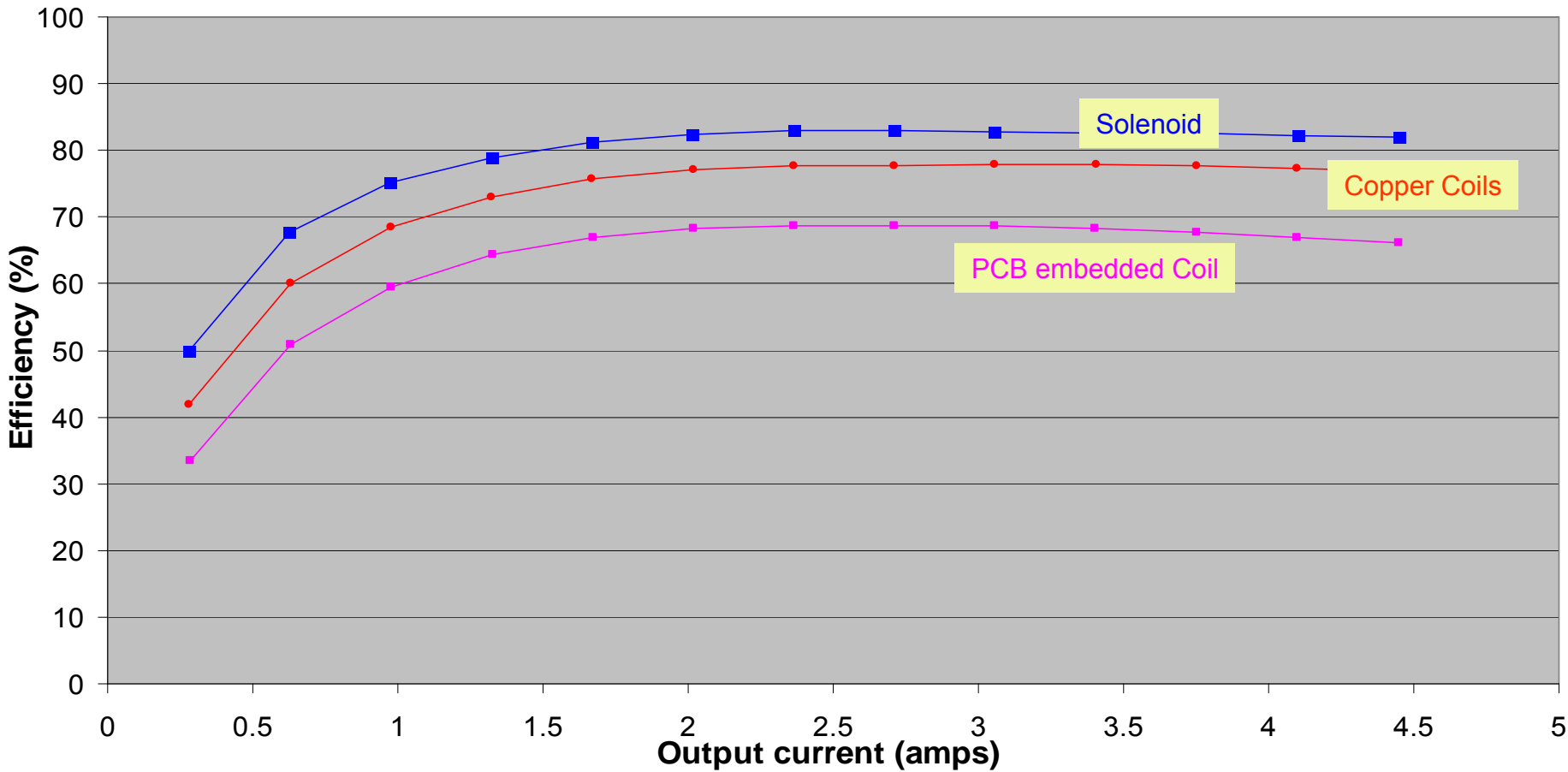
### ❖ Converter Chips

Max8654 monolithic  
IR8341 3 die MCM

### ❖ Coils

Embedded 3oz cu  
Solenoid 15 mΩ  
Spiral Etched 0.25mm

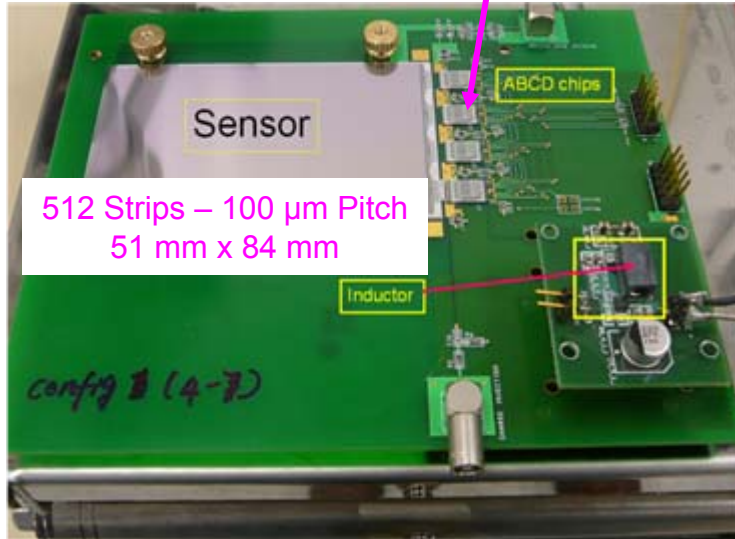
**MAX8654 with embedded coils (#12), external coils (#17) or Renco Solenoid (#2)  
V<sub>out</sub>=2.5 V**



—■— MAX #12, Vin = 11.9 V —●— MAX #17, Vin = 11.8 V —■— MAX #2, Vin = 12.0 V

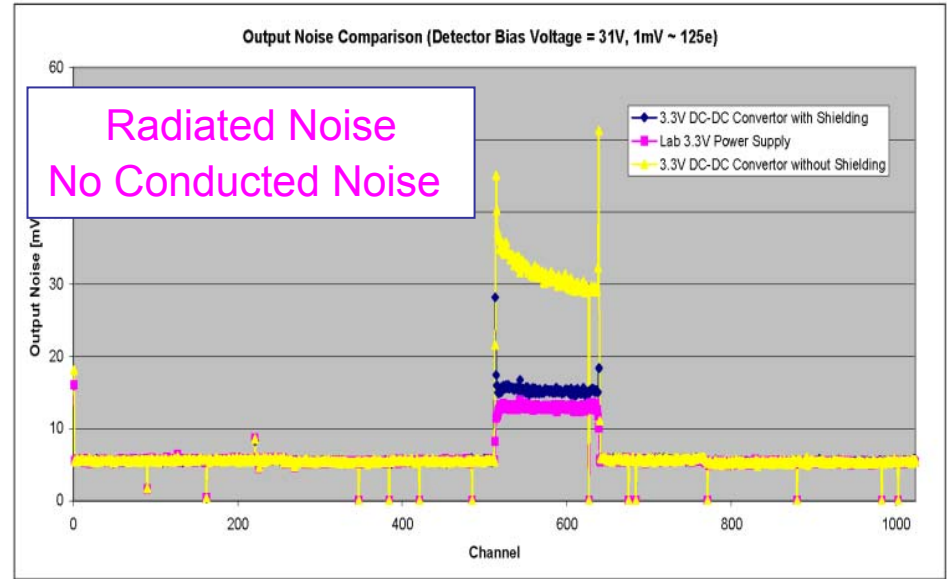
Test @ BNL

Only One Chip Bonded



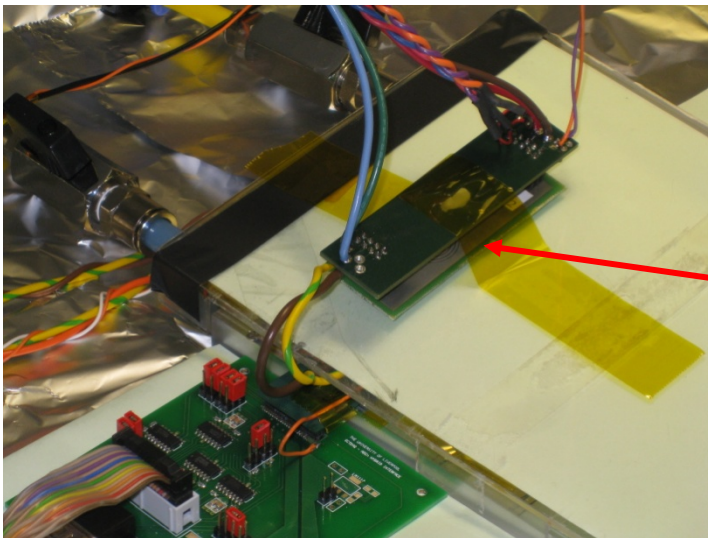
512 Strips – 100  $\mu\text{m}$  Pitch  
51 mm x 84 mm

# Noise Tests with Silicon Sensors



Radiated Noise  
No Conducted Noise

Test @ Liverpool



Plug in Card  
1 cm from Coil  
facing Sensor

20  $\mu\text{m}$  Al foil  
shielding

| Coil Type   | Power   | Input Noise electrons rms |
|-------------|---------|---------------------------|
| Solenoid    | DC - DC | 881                       |
| Solenoid    | Linear  | 885                       |
| Spiral Coil | DC - DC | 666                       |
| Spiral Coil | Linear  | 664                       |



# Ionizing Radiation Results – Commercial Converters

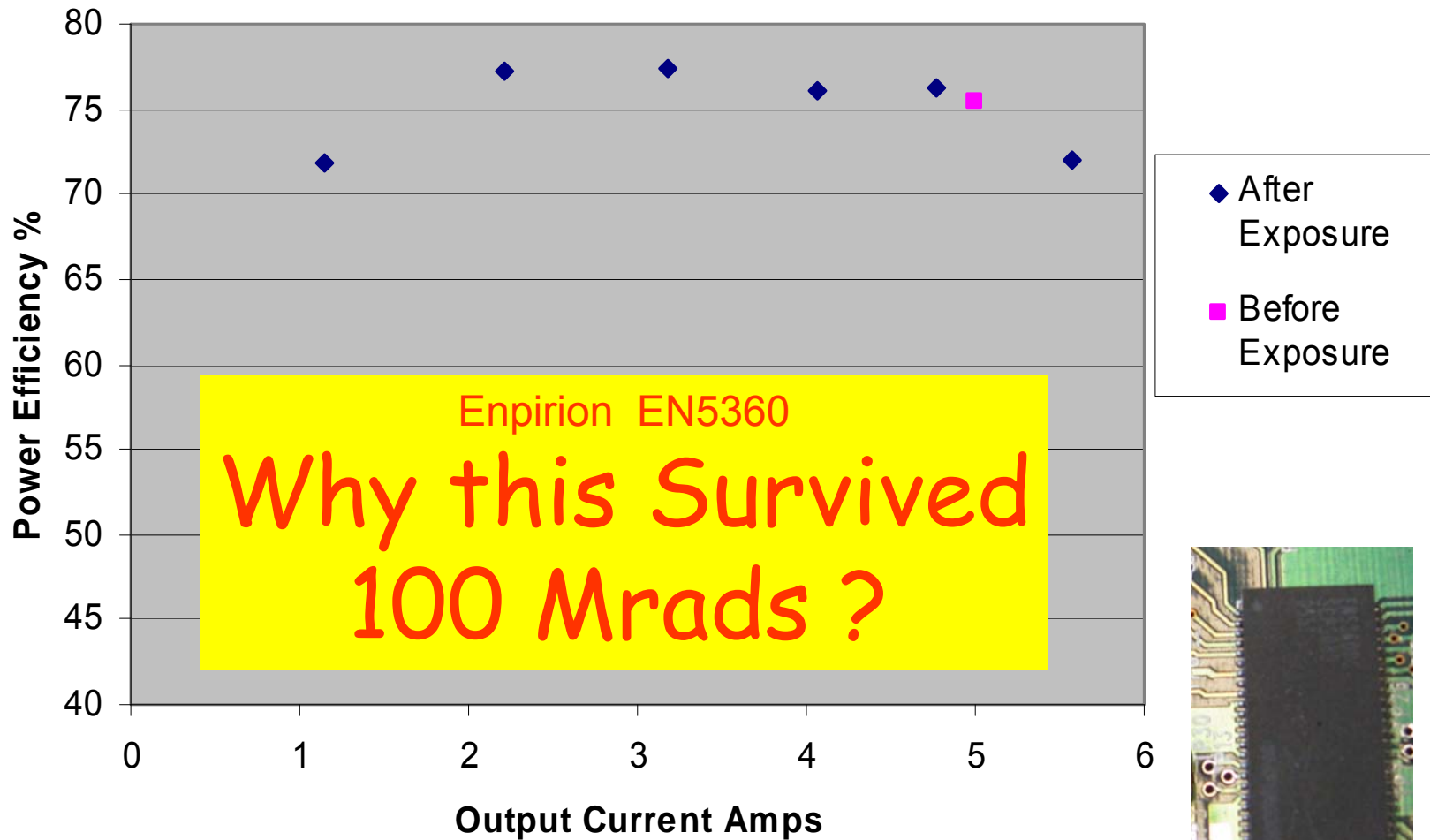
| Company        | Device    | Oxide Thickness (nm) | Dose before Damage | Observation Damage Mode           |
|----------------|-----------|----------------------|--------------------|-----------------------------------|
| IHP            | ASIC      | 5                    | 53 Mrad            | slight damage                     |
| XYSemi         | MOS FET   | 7                    | 52 Mrad            | Minimal damage                    |
| XYSemi         | XP5062    | 12.3                 | 44 krad            | Loss of output voltage regulation |
| TI             | TPS54620  | 20                   | 23 krad            | abrupt failure                    |
| Intersil       | ISL 8502  | unknown              | 40.6 krad          | Increasing input current          |
| IR             | IR3822    | unknown              | 139 krads          | Increasing input current          |
| IR             | IR3841    | 9 & 25               | 13 krads           | Loss of output voltage regulation |
| ST             | ST1510    | unknown              | 125 krad           | Loss of output voltage regulation |
| Enpirion       | EN5365    | 5                    | 85 krad            | Increasing input current,         |
| Enpirion       | EN5382    | 5                    | 111 krads          | Loss of output voltage regulation |
| Enpirion       | EN5360 #2 | 5                    | 100 Mrads          | No significant Changes            |
| Enpirion       | EN5360 #3 | 5                    | 48 Mrads           | No significant changes            |
| National Semi. | LM2864    | 11.8                 | 3 Mrads            | Short after power recycle         |

Dose rate= 0.2 Mrad/hr

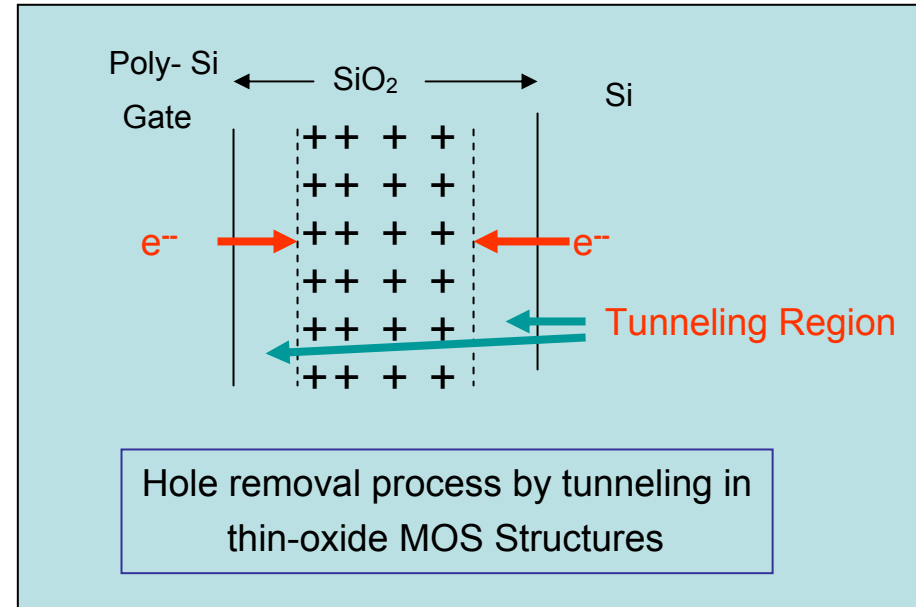
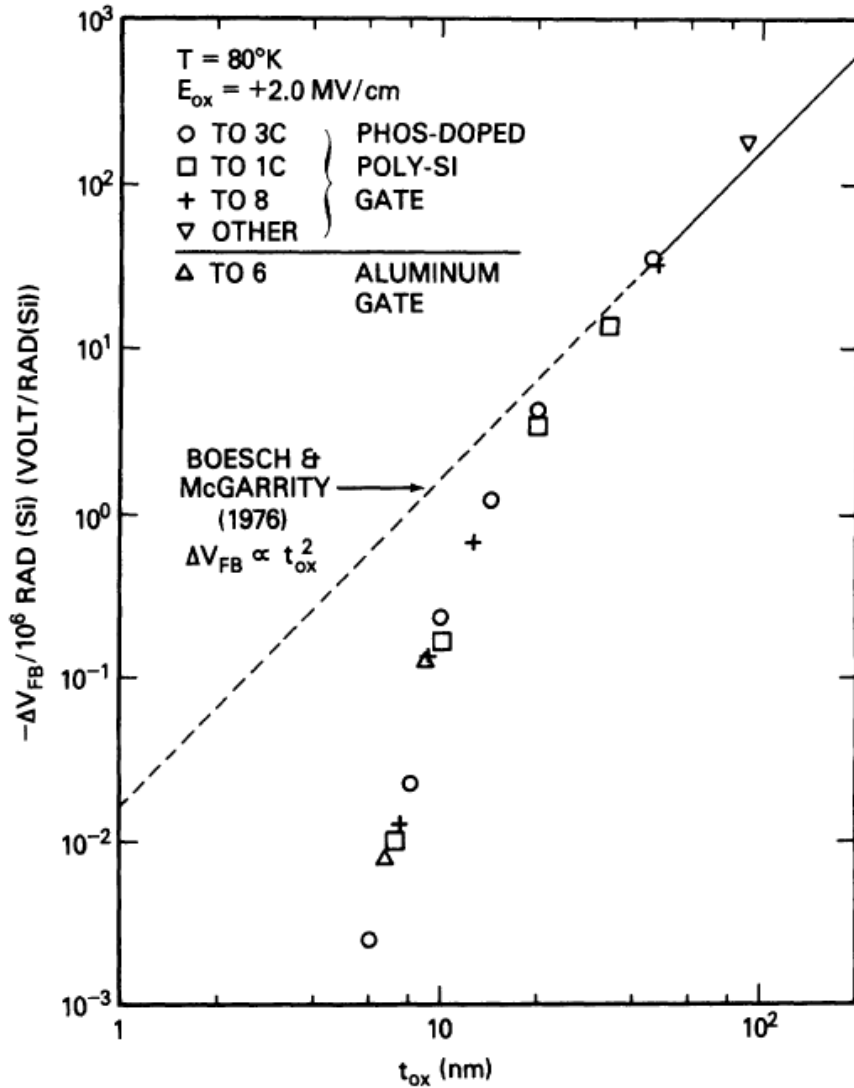
5- 12 nm Gate Oxide

Many more tested but similar failure-  
Thin oxide converters survive > 200 Krads

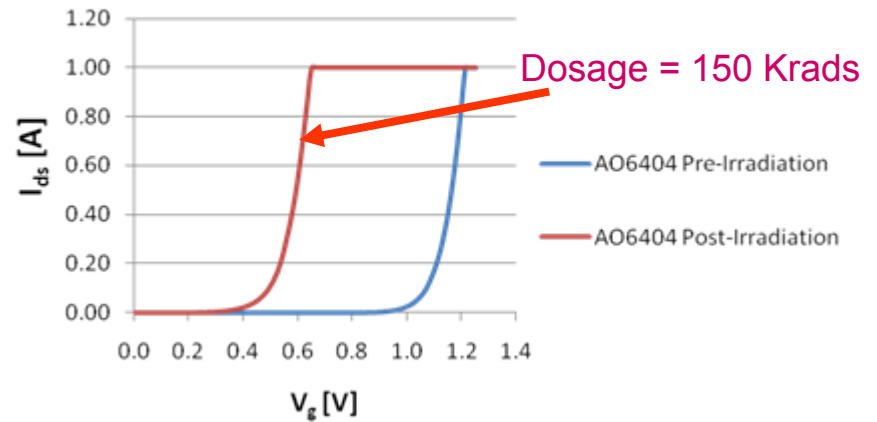
# Buck Regulator Efficiency after 100 Mrad dosage



# Threshold Shift vs Gate Oxide Thickness



Shifting  $V_t$  of MOSFET With Gammas



Sachs et. al. IEEE Trans. Nuclear Science NS-31, 1249 (1984)

Book. Timothy R Oldham "Ionizing Radiation Effects in MOS Oxides" 1999 World Scientific



# Can We Have High Radiation Tolerance & Higher Voltage Together ???

Higher radiation tolerance needs thin oxide  
while higher voltage needs thicker oxide – Contradiction ?

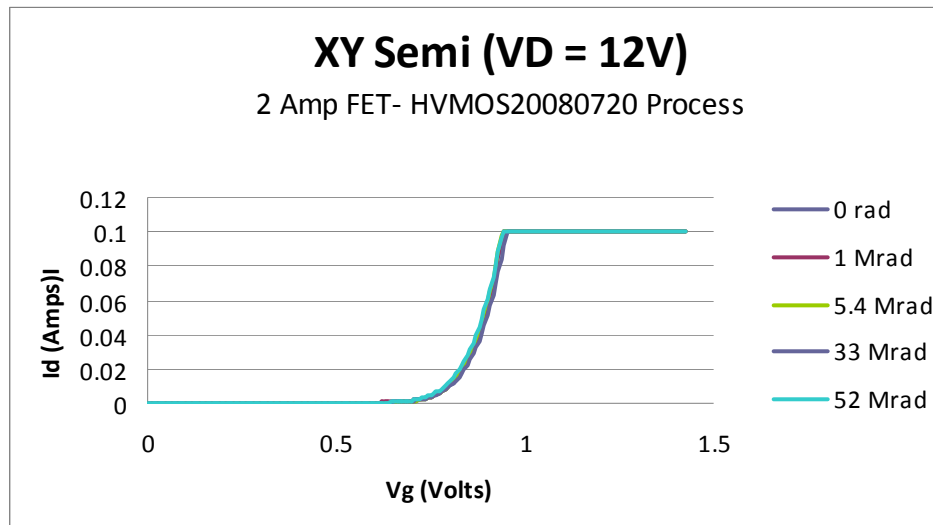
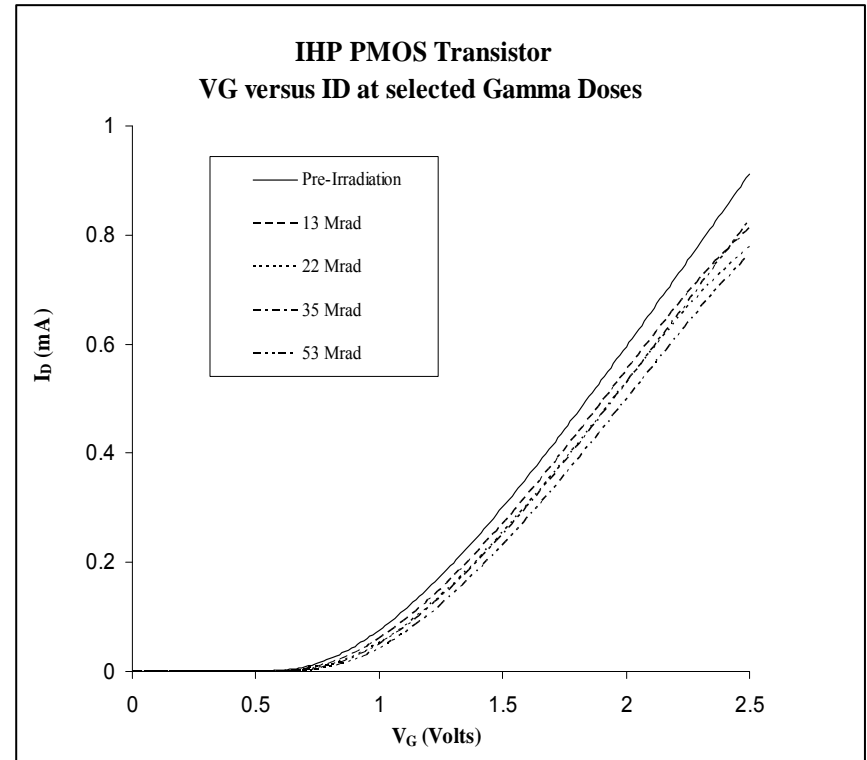
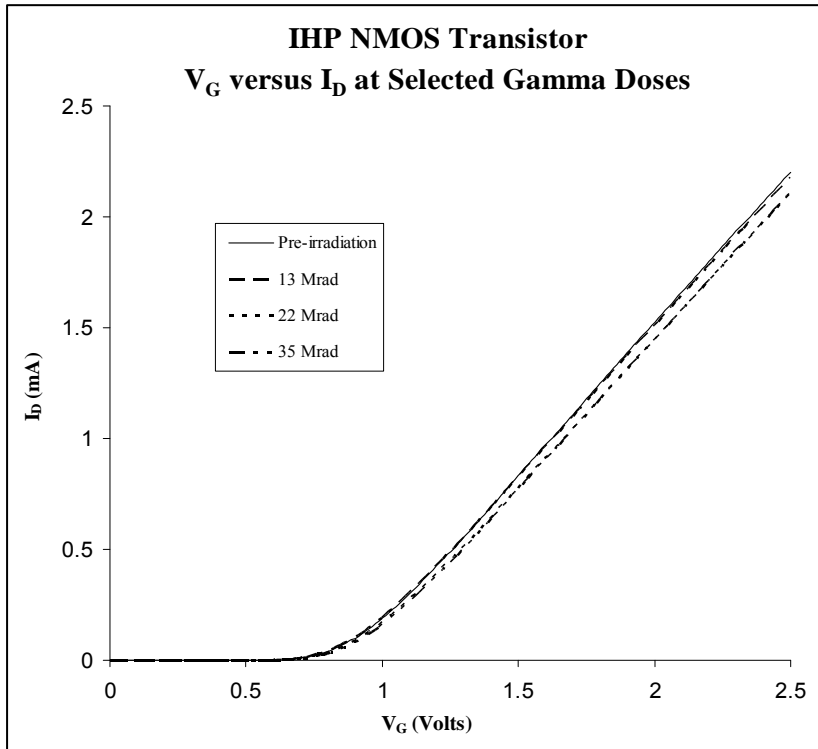
Mixed signal power designs from TI, TSMC, IBM etc - 0.18  $\mu\text{m}$  & 0.13  $\mu\text{m}$   
Automobile Market. Voltage ratings 10 - 80 Volts  
Deep sub-micron but thick oxide

Controller : Low Voltage

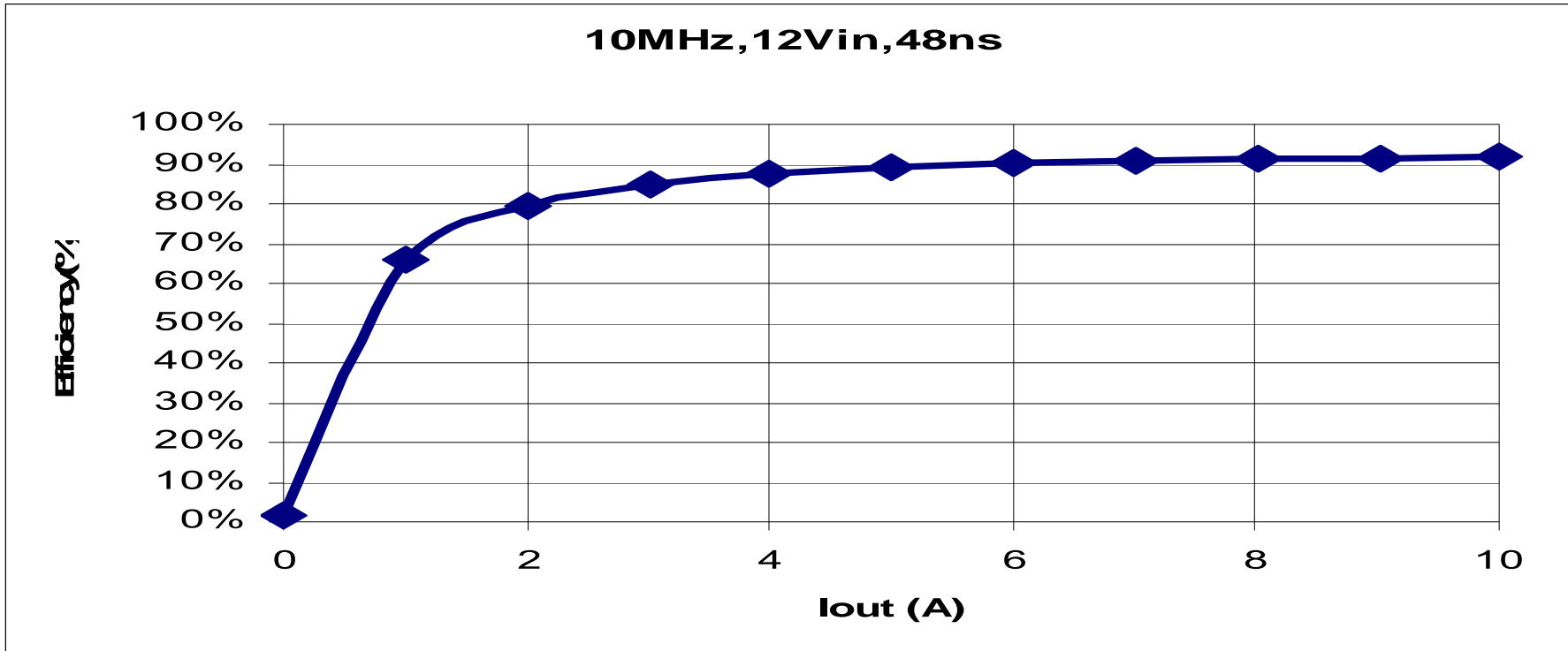
High Voltage: Switches – some candidates HV & Thin oxide

RF Process LDMOS, Drain Extension, Deep Diffusion etc

>> 20 Volts HEMT GaN on Silicon, Silicon Carbide, Sapphire



Frequency Response IR's Engineering sample in 2009  
Half Bridge with CMOS Driver



*Good efficiency to >12 MHz Driver limited*

International Rectifier: Supplied sample board under NDA

# Radiation Results – RF GaN & EPC GaN on Si

## Nitronex 25015 $5 \times 10^{14}$ Neutrons/cm<sup>2</sup>

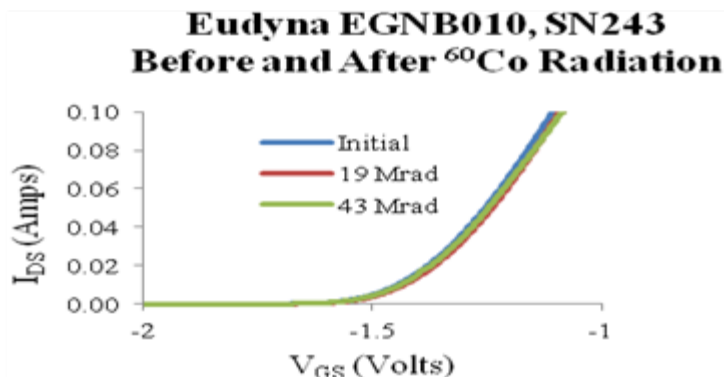


Fig. 7. Eudyna EGNB010 GaN HEMT, VGS versus IDS at VDS = 10 volts and selected doses of 60Co gamma radiation. Little change is apparent even after 43 Mrad of ionizing radiation.

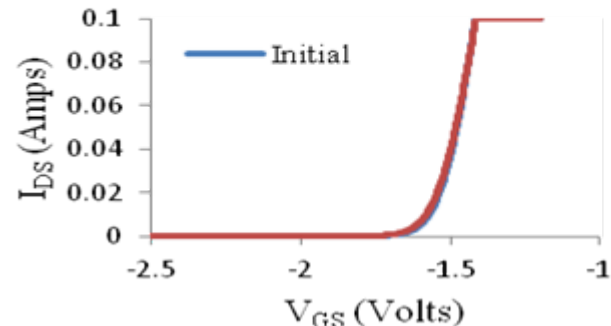


Fig. 6. Nitronex 25015 HEMT irradiate with  $5 \times 10^{14}$  neutrons (1 MeV equivalent). Little change is observed in the response.

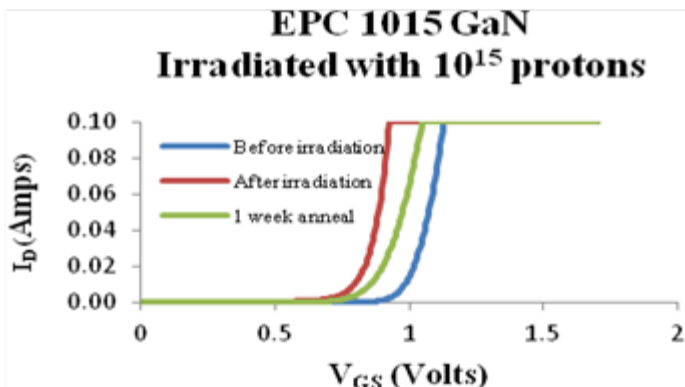


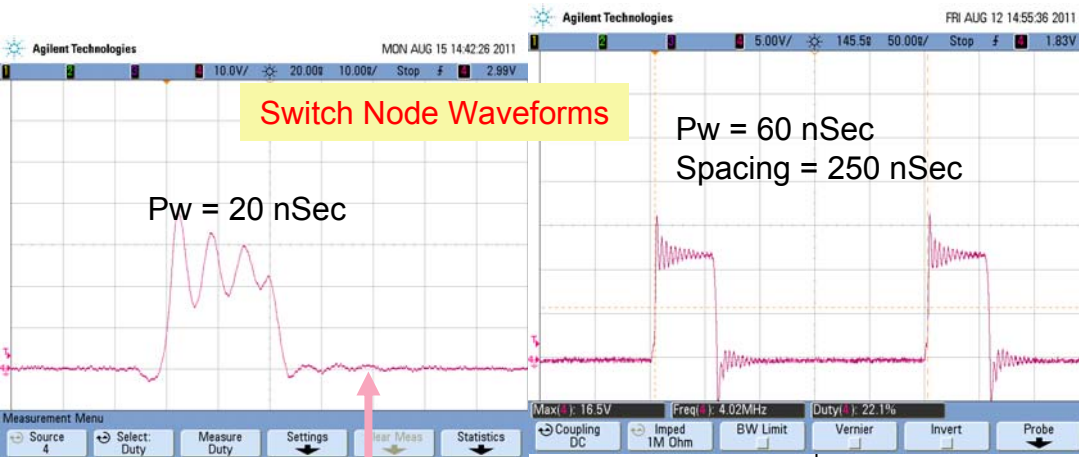
Fig. 8. EPC 1015 HEMT before and after  $10^{15}$  protons/cm<sup>2</sup>. During exposure VDS = 24V with a 1 kOhm resistor current limiting the channel to 24 mA. The device was “clocked” with a VGS = 4 V at a 1 kHz frequency

TABLE III Radiation Testing Matrix for GaN Devices

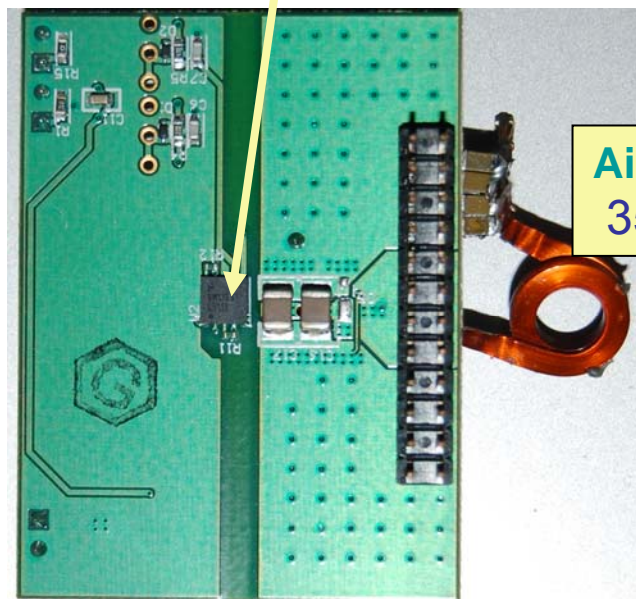
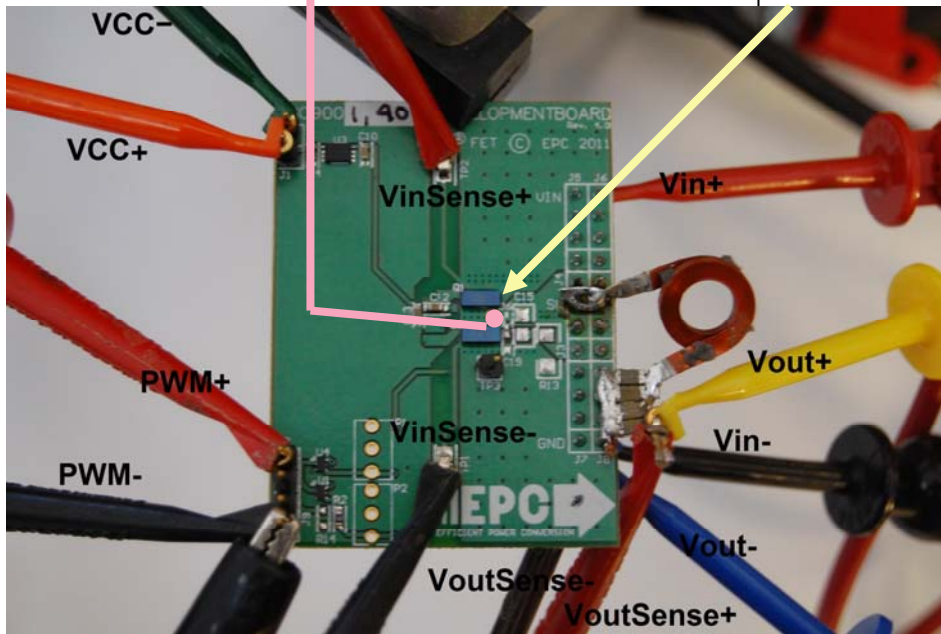
| Company  | Device  | <sup>60</sup> Co | Neutron Fluence (cm <sup>-2</sup> ) | Proton Fluence (cm <sup>-2</sup> ) |
|----------|---------|------------------|-------------------------------------|------------------------------------|
| Nitronex | 25015   | 17.4Mrad         | $5 \times 10^{14}$                  | $1 \times 10^{15}$                 |
| Cree     | 40010   |                  | $5 \times 10^{14}$                  | $1 \times 10^{15}$                 |
| Eudyna   | EGNB010 | 43 Mrad          | $5 \times 10^{14}$                  | $1 \times 10^{15}$                 |
| EPC      | EPC1015 | 64 Mrad          |                                     | $1 \times 10^{15}$                 |



# eGaN with discrete & LM5113 Driver

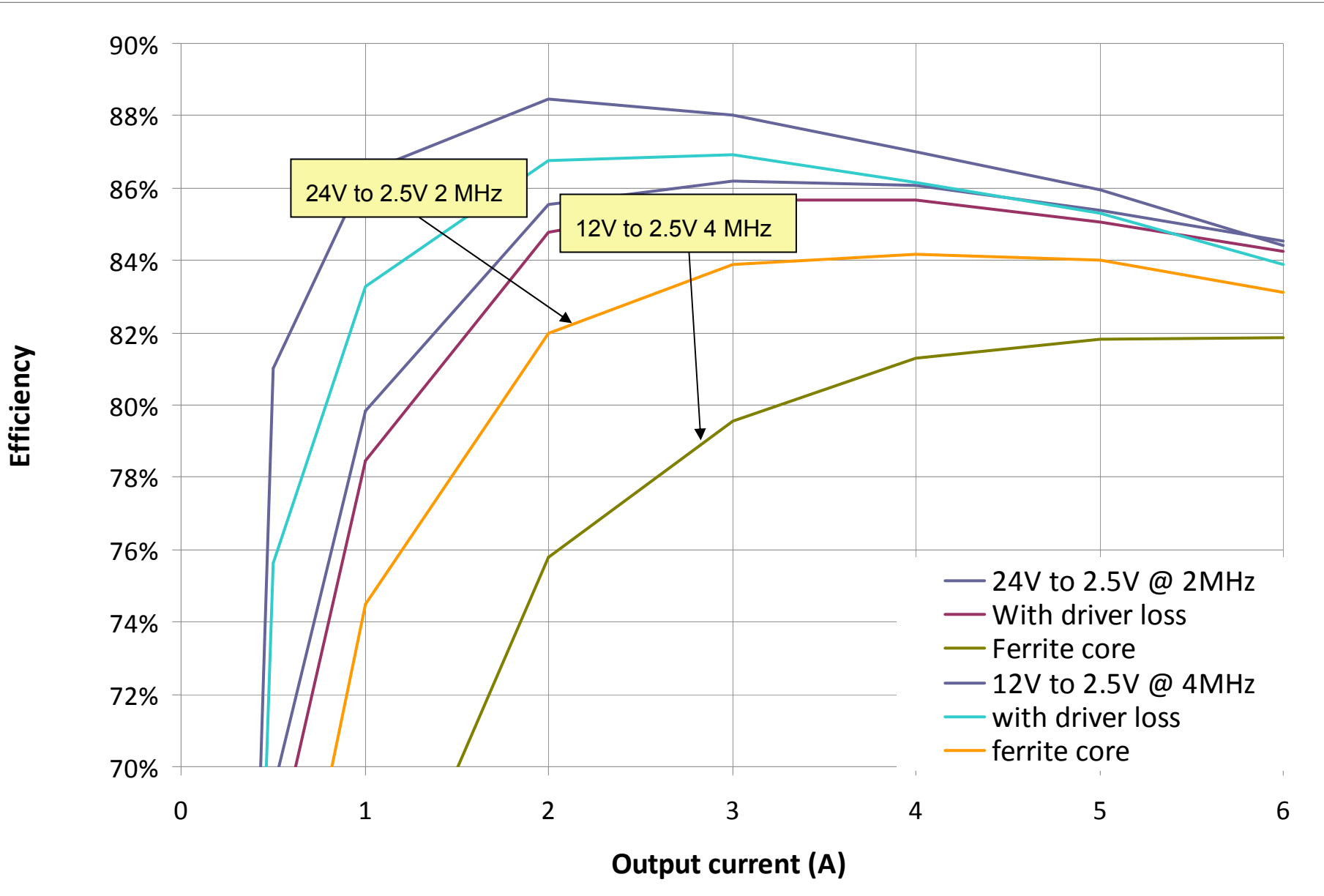


National eGaN Driver LM5113 on Bottom  
eGaN on Top side



Air Core Coil  
355 nH

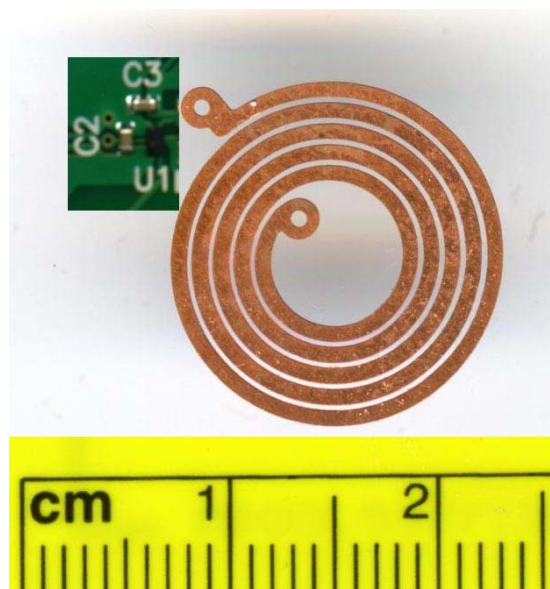
Aircoil EPCOS-B82559A0392A013 3.9  $\mu$ H / 355 nH without Ferrite. 5 m $\Omega$



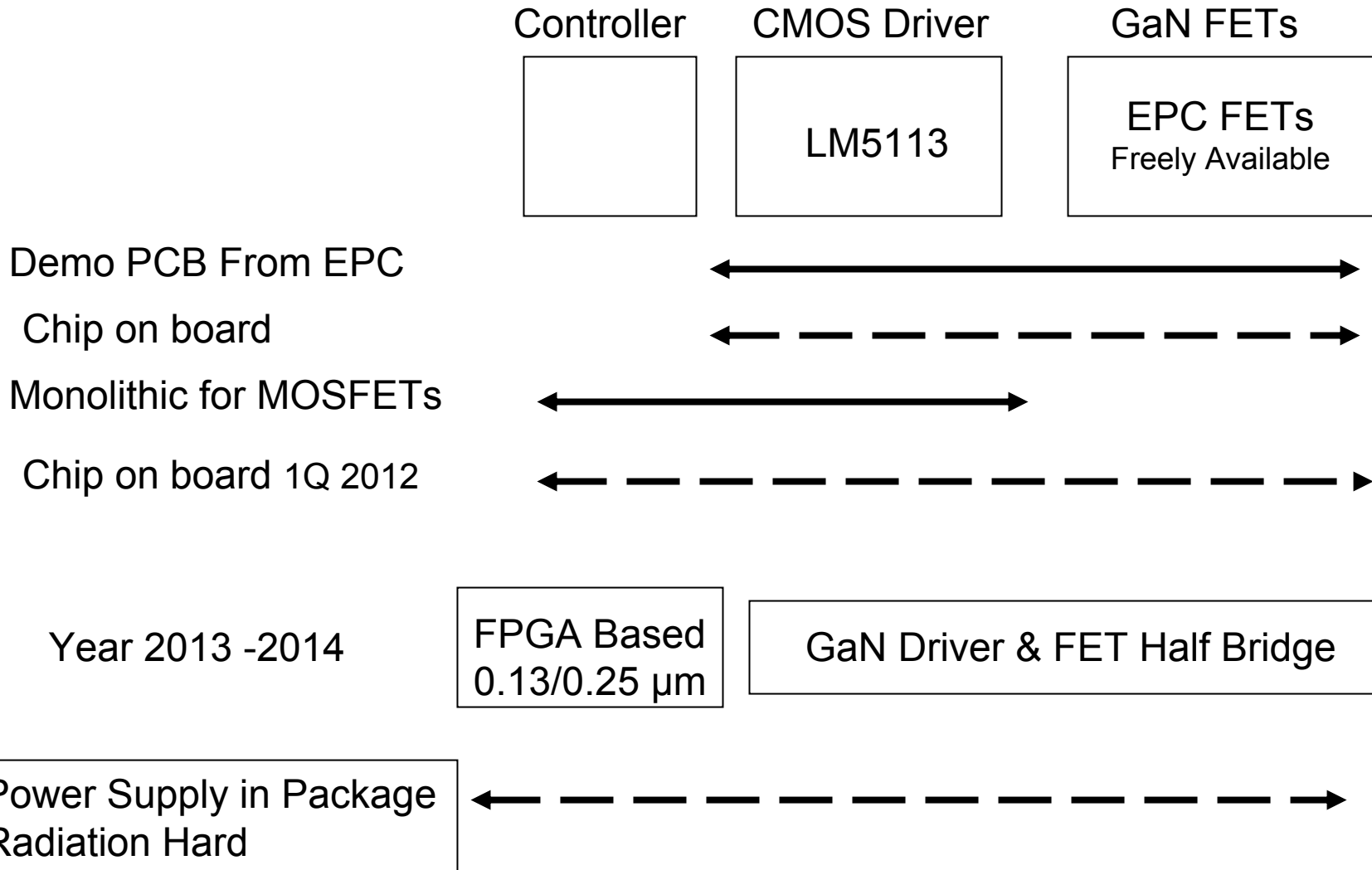
# Electron Linear Collider produce low radiation

but material in the interaction regions must be minimized


- ❖ High Frequency operation for lower coil size / material
- ❖ Commercial cell phone converters 6 - 8 MHz, 1 amp, 5.5 Vin
- ❖ 1 -2 turn coil
- ❖ Fabricate PCB & Test
- ❖ Power Supply in a Package
- ❖ Coil simulation needs collaborators ??
- ❖ Coil may be buried in the detector PCB
- ❖ Feasibility report due summer 2012



# Market Trend





A polar bear stands on a vast, flat expanse of snow and ice. To the left, there is a large, dark, irregular hole in the ice. The bear is facing right, and its shadow is cast to the left. The ground is covered in numerous small, circular tracks, likely from the bear or other animals. The overall scene is desolate and cold.

# Working on Physics Power Supply Is not considered Glamorous

Top of the World is Cool but lonely !  
Let us keep it cool with highly efficient PS  
Swimming is Great at the North Pole  
August 2010 Fairbanks, Alaska was 33 C - Bye Bye Glaciers !

**More Details:** <http://shaktipower.sites.yale.edu> Click on Recent seminars/